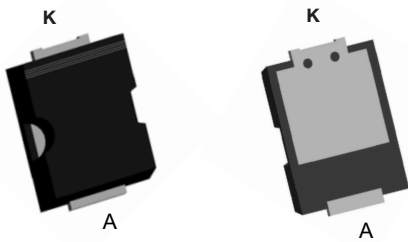


Ultra Low Leakage Current Rectifier Schottky

SS8P100P6 SMP6



Cathode K  Anode A

Features

- Advanced trench technology
- Low forward voltage drop
- Ultra Low Leakage Current 1uA Max
- High efficiency operation
- Lead Free Finish, RoHS Compliant

Applications

- DC/DC Converters
- AC/DC Adaptors
- Switching Power Supplies
- Freewheeling Diodes

Maximum ratings and electrical characteristics (TJ = 25°C unless otherwise noted)

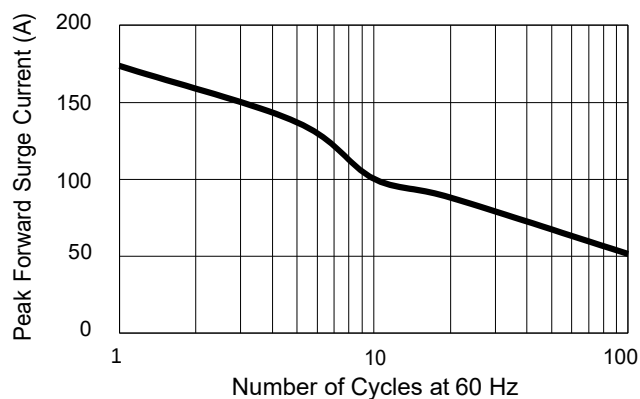
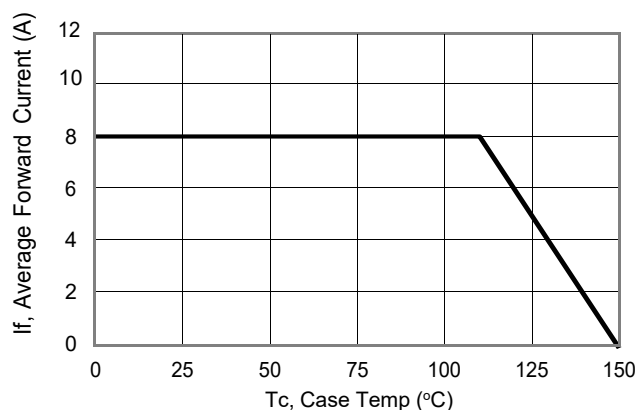
Parameter			Symbol	Limit		Unit
Maximum repetitive peak reverse voltage			VRRM	100		V
Maximum average forward rectified current			IF(AV)	8.0		A
Peak forward surge current 8.3 ms single half sine- wave superimposed on rated load per diode			IFSM	170		A
Operating junction and storage temperature range			TJ, TSTG	-50 to +150		°C
Typical thermal resistance per diode(Mounted on FR-4 PCB)			RθJC	72		°C/W
Instantaneous forward voltage per diode			VF(1)	TYP.	MAX.	V
	IF=2A	TJ=25°C		0.73	0.78	
	IF=2A	TJ=125°C		0.68	-	
	IF=8A	TJ=25°C		0.90	0.95	
	IF=8A	TJ=125°C		0.85	-	
Instantaneous reverse current per diode at rated reverse voltage		TJ=25°C	IR(2)	-	1	uA
		TJ=125°C		5	-	uA

Notes:

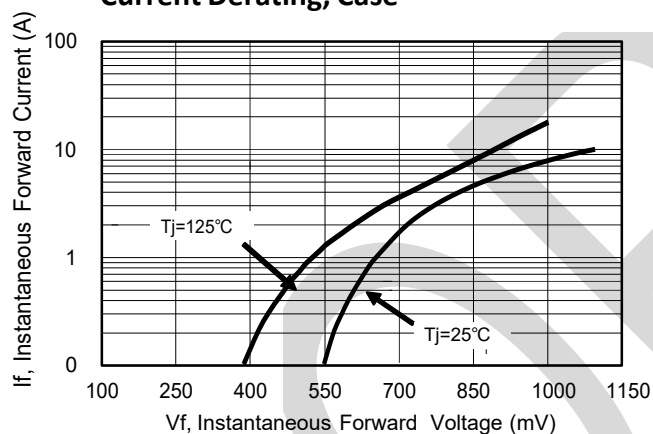
(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

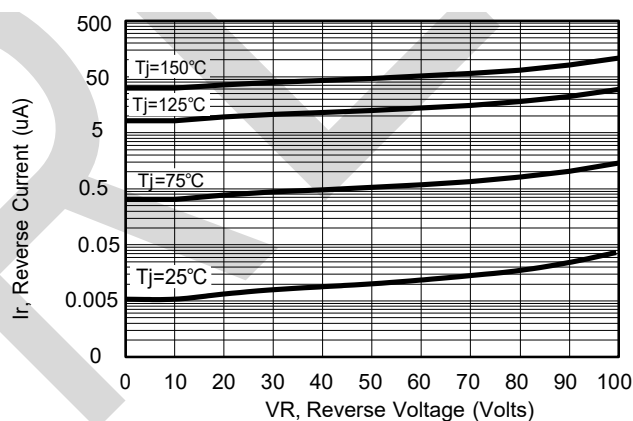
RATINGS AND CHARACTERISTICS CURVES (TA = 25 °C unless otherwise noted)



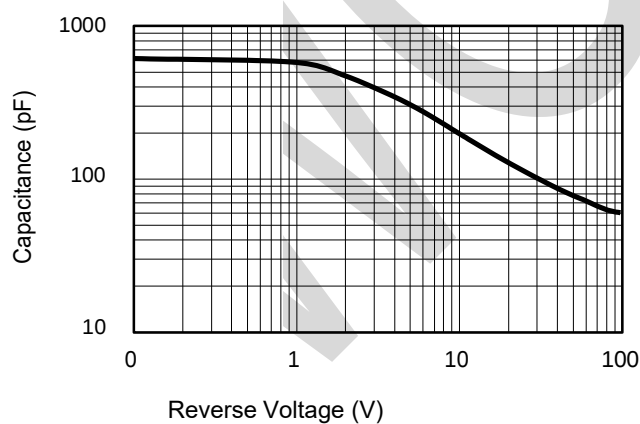
Current Derating, Case



Maximum Repetitive Surge Current



Typical Forward Voltage

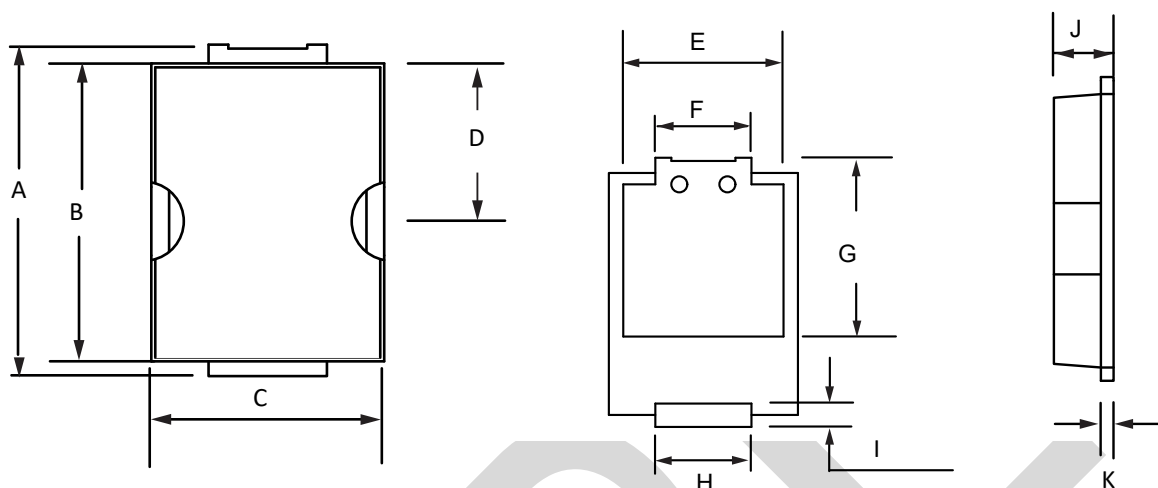


Typical Reverse Current

Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS

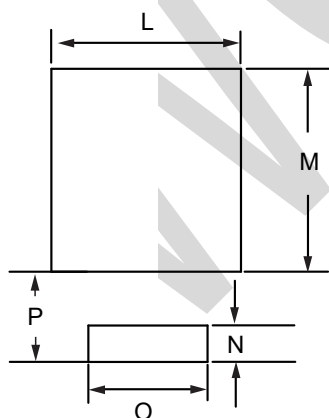
SMP6



SMP6 mechanical data

UNIT		A	B	C	D	E	F	G	H	I	J	K
mm	max	8.6	7.75	6.1	4.2	5.2	3.2	5.68	3.2	0.93	1.85	0.45
	min	8.0	7.35	5.7	3.8	4.8	2.8	5.28	2.8	0.53	1.45	0.25
mil	max	338.5	305.1	240.1	165.3	204.7	126.0	223.6	126.0	36.6	72.8	17.7
	min	314.9	289.3	224.4	149.6	188.9	110.2	207.8	110.2	20.8	57.1	9.8

SMP6 Suggested Pad Layout



UNIT		L	M	N	O	P
mm	min	5.40	5.78	1.0	3.4	1.8
mil	min	212.6	227.5	39.3	133.8	70.8